

FEATURES

- Adopt FRED chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

TYPICAL APPLICATIONS

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MECHANICAL DATA

- **Package:** TO-252
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

MAXIMUM RATINGS (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR1040D
Device marking code			MUR1040D
Repetitive Peak Reverse Voltage	V _{RRM}	V	400
Average Rectified Output Current @60Hz sine wave, R-load, T _c (FIG.1)	I _o	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C	I _{FSM}	A	120
Current Squared Time @1ms≤t≤8.3ms T _j =25°C,	I ² t	A ² s	60
Storage Temperature	T _{stg}	°C	-55 ~ +150
Junction Temperature	T _j	°C	-55 ~ +150
Junction capacitance @4V,1MHz	C _j	pF	50

ELECTRICAL CHARACTERISTICS (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Instantaneous forward voltage drop per diode	V _{FM}	V	I _{FM} =10.0A @T _j =25°C	-	1.15	1.25
			I _{FM} =10.0A @T _j =150°C	-	0.9	1
DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	uA	V _{RM} =V _{RRM} T _j =25°C	-	-	5
	I _{RRM2}		V _{RM} =V _{RRM} T _j =150°C	-	40	200
Reverse Recovery Time	T _{RR}	ns	I _F =0.5A I _{RM} =1A I _{RR} =0.25A T _j =25°C	-	25	35
Peak recovery current	I _{RRM}	A	T _j =25°C	-	4.67	-
			T _j =125°C	-	7.68	-
Reverse recovery charge	Q _{rr}	nC	T _j =25°C	I _F =10A di/dt=-200A/us V _{RM} =200V	-	164.31
			T _j =125°C		-	371.34

■ **THERMAL CHARACTERISTICS** ($T_a=25^{\circ}\text{C}$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MUR1040D
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^{\circ}\text{C/W}$	5.0
	Between junction and Air	$R_{\theta J-A}$	$^{\circ}\text{C/W}$	50

■ **PACKAGING INFORMATION**

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR1040D	Approximate 0.31	2500	2500	25000	Reel

■ **CHARACTERISTICS (TYPICAL)**

FIG1: I_o - T_c Curve

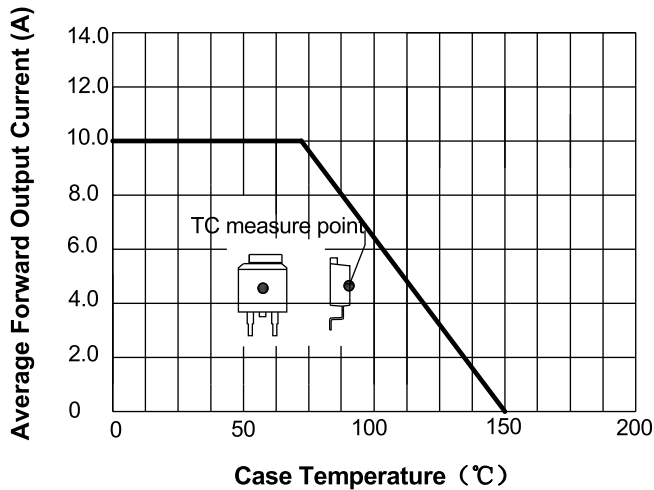


FIG2: Surge Forward Current Capability

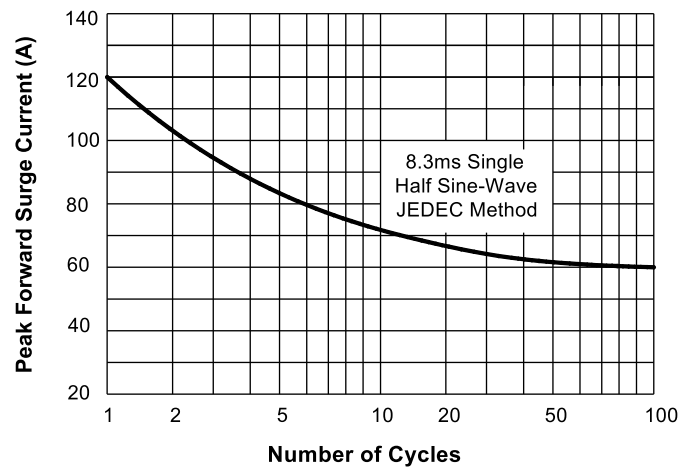


FIG3: Forward Voltage

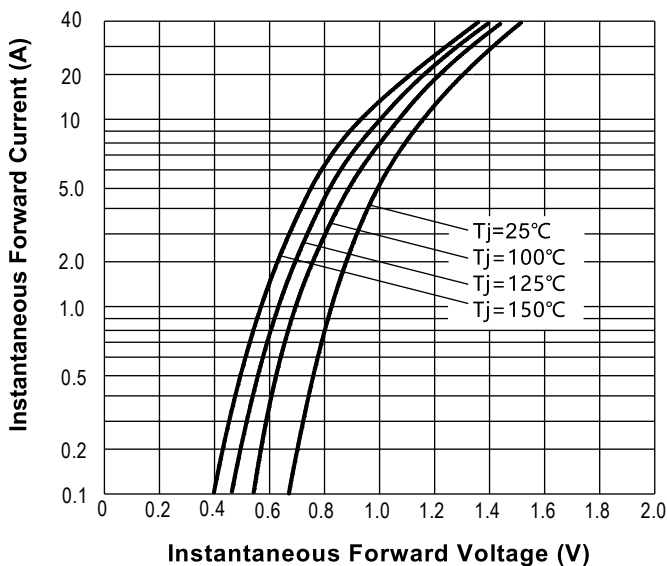


FIG4: Instantaneous Reverse Characteristics

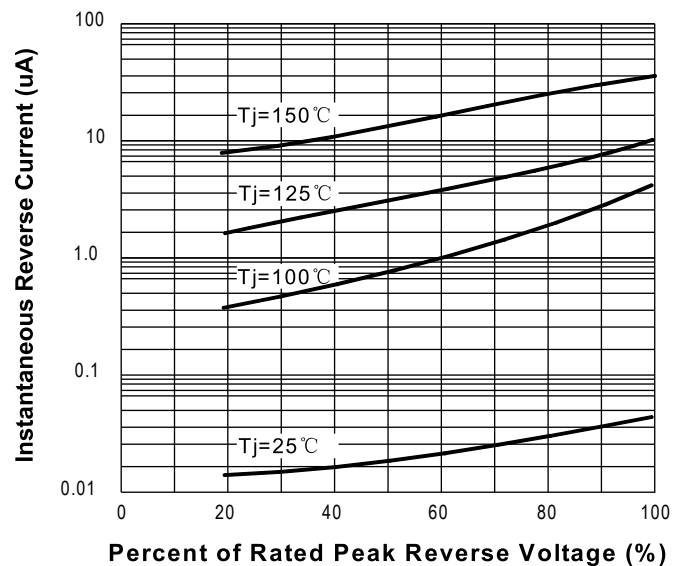
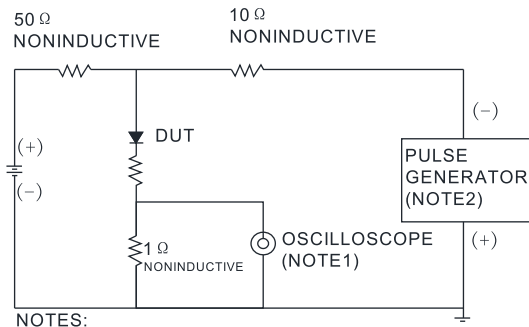
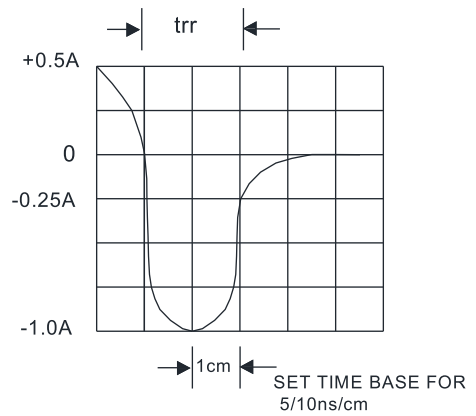


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

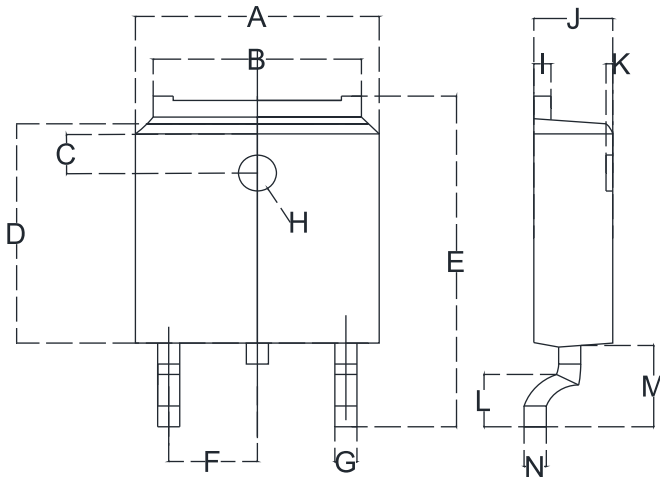


NOTES:
1. Rise Time=7ns max .Inpot Impedance=1M Ω 22pf
2. Rise Time=10ns max.Source Impedance=50 Ω



■ **OUTLINE DIMENSIONS**

TO-252



TO-252		
Dim	Min	Max
A	6.500	6.700
B	5.100	5.460
C	1.400	1.800
D	6.000	6.200
E	10.000	10.400
F	2.166	2.366
G	0.660	0.860
H	Φ 1.050	Φ 1.350
I	0.460	0.580
J	2.200	2.400
K	0	0.300
L	0.890	2.290
M	2.730	3.080
N	0.430	0.580